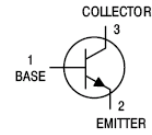


Features

- Epitaxial planar die construction
- Ultra-small surface mount package
- High current gain bandwidth product
- Halogen free
- Qualified to AEC-Q101 standards for high reliability

HF



SOT-23

Mechanical Data

- Case: SOT-23
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
TS9018	SOT-23	3000 pcs / Tape & Reel	J8

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Breakdown Voltage	V _{CBO}	25	V
Collector-Emitter Breakdown Voltage	V _{CEO}	18	V
Emitter-Base Breakdown Voltage	V _{EBO}	4	V
Continuous Collector Current	I _C	50	mA

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation	P _D	200	mW
Operating junction Temperature	T _J	-55 ~ +150	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 100\mu\text{A}, I_E = 0$	25	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 0.1\text{mA}, I_B = 0$	18	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 100\mu\text{A}, I_C = 0$	4	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB} = 20\text{V}, I_E = 0$	-	-	0.1	μA
Collector cut-off current	I_{CEO}	$V_{CE} = 15\text{V}, I_B = 0$	-	-	0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 3\text{V}, I_C = 0$	-	-	0.1	μA
DC current gain	h_{FE}	$V_{CE} = 5\text{V}, I_C = 1\text{mA}$	70	-	190	-
Collector-emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 10\text{mA}, I_B = 1\text{mA}$	-	-	0.5	V
Base-emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 10\text{mA}, I_B = 1\text{mA}$	-	-	1.4	V
Transition Frequency	f_T	$I_C = 5\text{mA}, V_{CE} = 5\text{V}, f = 400\text{MHz}$	600	-	-	MHz

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

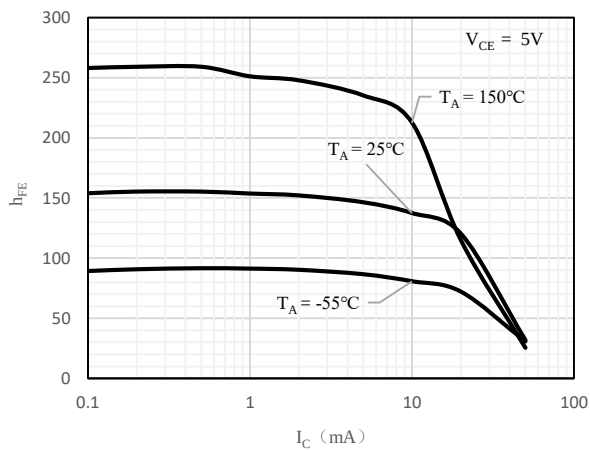


Fig 1 h_{FE} vs. I_C

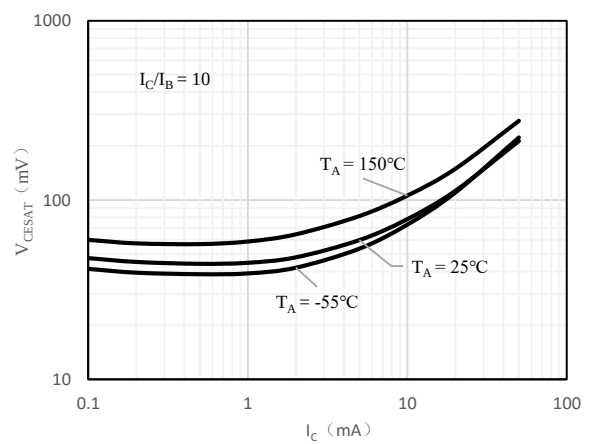


Fig 2 $V_{CE(sat)}$ vs. I_C

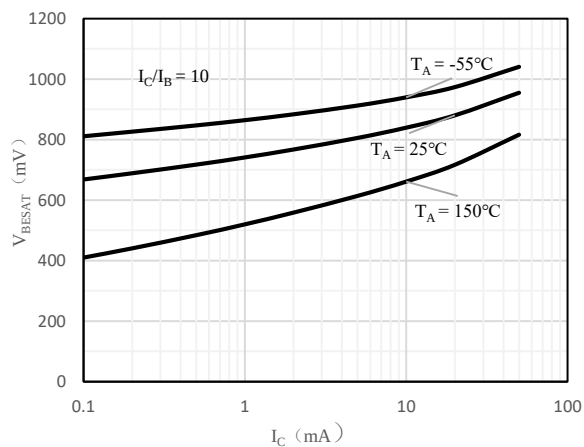


Fig 3 $V_{BE(sat)}$ vs. I_C

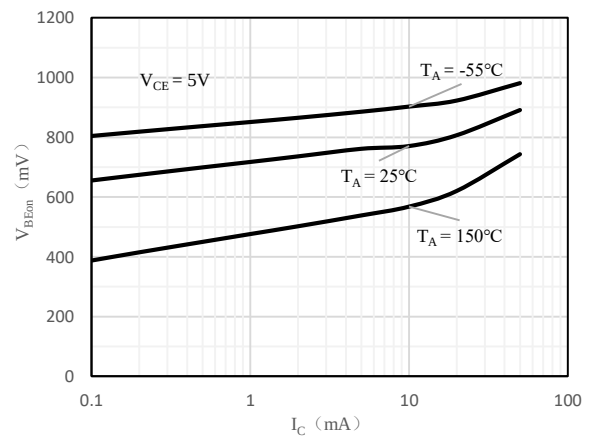
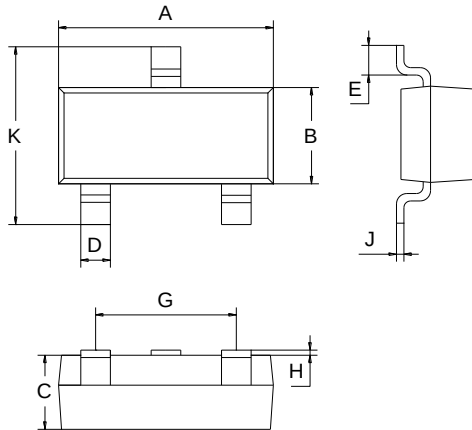


Fig 4 $V_{BE(on)}$ vs. I_C

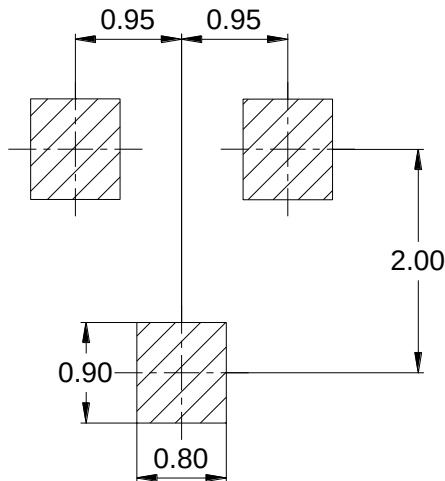
Package Outline Dimensions (Unit: mm)



SOT-23		
Dimension	Min.	Max.
A	2.70	3.10
B	1.10	1.50
C	0.9	1.1
D	0.3	0.5
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.05	0.15
K	2.20	2.60

Package Outline Dimensions (Unit: mm)

SOT-23



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